OM SENI

BAT54CTT1G
Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage − 0.35 Volts (Typ) @ I_F = 10 mAdc
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

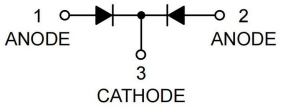
MAXIMUM RATINGS (T_J = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	30	V
Forward Power Dissipation @ T_A = 25°C Derate above 25°C	P_F	 225 1.8	 mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	 555	°C/W
Forward Current (DC)	I_F	200 Max	mA
Non−Repetitive Peak Forward Current, t_p < 10 msec	I_{FSM}	 600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	I_{FRM}	 300	mA
Junction Temperature	T_J	−55 to 125	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C

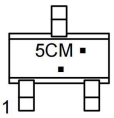
30 VOLT
DUAL COMMON CATHODE
SCHOTTKY BARRIER DIODES



SOT-523



MARKING DIAGRAM



5C = Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending up-on manufacturing location.

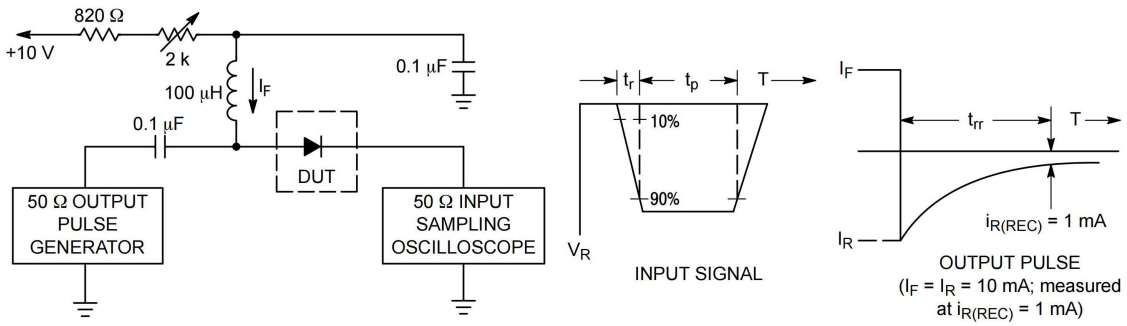
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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage (I_R = 10 μA)	$V_{(BR)R}$	30	–	–	V
Total Capacitance (V_R = 1.0 V, f = 1.0 MHz)	C_T	–	7.6	10	pF
Reverse Leakage (V_R = 25 V)	I_R	–	0.5	2.0	μAdc
Forward Voltage (I_F = 0.1 mA) (I_F = 1.0 mA) (I_F = 10 mA) (I_F = 30 mA) (I_F = 100 mA)	V_F	 – – – – –	 0.22 0.29 0.35 0.41 0.52	 0.24 0.32 0.40 0.50 0.80	V
Reverse Recovery Time (I_F = I_R = 10 mAdc, $I_{R(REC)}$ = 1.0 mAdc, Figure 1)	t_{rr}	–	–	5.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10 mA.
2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

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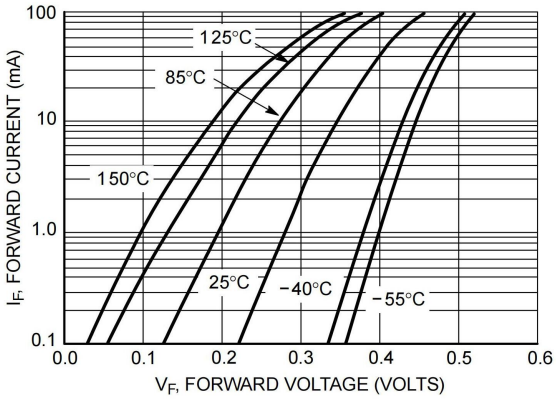


Figure 2. Forward Voltage

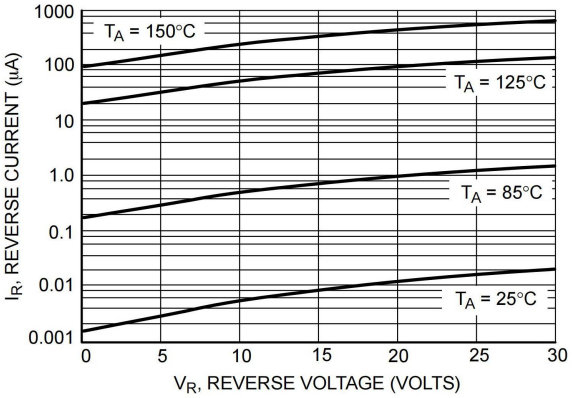


Figure 3. Leakage Current

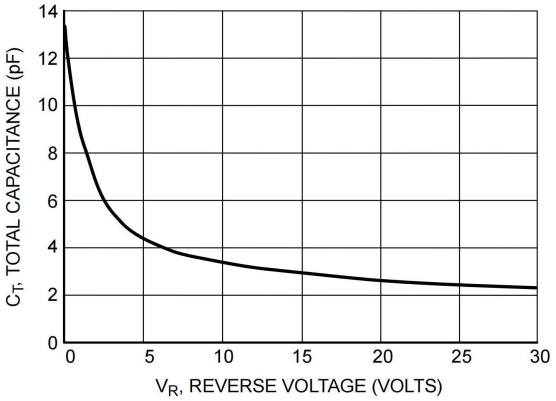


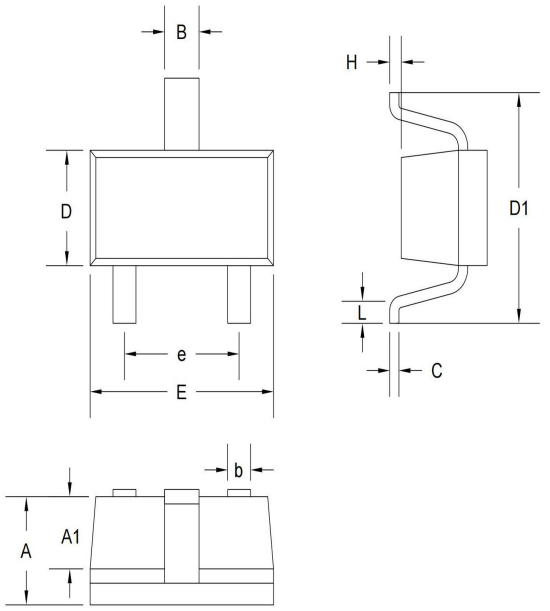
Figure 4. Total Capacitance

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Ordering Information

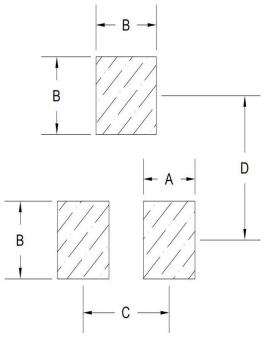
PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-523	R1	0.0025	3000	30000	240000	7"

Package Outline Dimensions (SOT-523)



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.65	0.85	0.026	0.033
A1	0.40	0.60	0.016	0.024
B	0.25	0.35	0.010	0.014
b	0.15	0.25	0.006	0.010
C	0.05	0.15	0.002	0.006
D	0.70	0.90	0.028	0.035
D1	1.50	1.70	0.059	0.067
E	1.5	1.7	0.059	0.067
e	0.95	1.05	0.037	0.041
H	-	0.10	-	0.004
L	0.17	-	0.007	-

Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.50	0.70	0.020	0.028
B	0.60	0.80	0.024	0.031
C	0.90	1.10	0.035	0.043
D	1.20	1.40	0.047	0.055